Vivekananda College of Engineering & Technology,Puttur [A Unit of Vivekananda Vidyavardhaka Sangha Puttur ®]							
Affiliated to VTU, Belagavi & Approved by AICTE New Delhi							
CRM08	Rev 1.10	<ec></ec>	<16.06.2021>				

CONTINUOUS INTERNAL EVALUATION- 1

Dept: FY	Sem / Div: 2 A B C	Sub: Basic Electronics	S Code: 18ELN24				
Date: 26.06.2021	Time: 9:30-11:00	Max Marks: 50	Elective: N				
Note: Answer any 2 full questions, choosing one full question from each part.							

	Q	Questions	Marks	RBT	COs		
	IN	PART A					
1	a	Explain the working of PN-junction diode under forward and reverse biased conditions.	9	L2	CO1		
	b	Explain the working of half-wave rectifier with capacitor filter with neat circuit diagram and wave-forms.	9	L2	CO1		
	c	A full-wave rectifier uses two diodes having internal resistance of 20 Ω each. The transformer rms secondary voltage from centre to each end is 50 V. Find <i>Vm</i> , <i>Im</i> , <i>Idc</i> , <i>Vdc</i> and <i>Irms</i> if the load is 980 Ω .	7	L3	CO1		
	_	OR					
2	2 a	What is Zener diode? With neat circuit diagram, explain the operation of Zener diode voltage regulator with and without load?	9	L2	CO1		
	b	Explain Photo-diode, LED and Photo-coupler. Give minimum two applications of each.	9	L2	CO1		
	c	A half wave rectifier is fed from a supply of 230 V, 50 Hz with step down transformer of ratio 3:1. Resistive load connected is 2 k Ω . The diode forward resistance is 50 Ω and transformer secondary is 10 Ω . Calculate the DC load current and DC load voltage.	7	L3	CO1		
		PART B					
3	3 a	Explain construction, working and characteristics of N-channel JFET.	9	L2	CO2		
	b	Explain CMOS as an Inverter with neat circuit diagram. Give its equivalent circuit and its advantages.	9	L3	CO2		
	c	For a JFET, (i) $I_{DSS} = 9mA$ and $V_{GS(off)} = -8V$ (max); determine drain current for $V_{GS} = -4V$. (ii) $I_{DSS} = 10 \ mA$ and drain current 5 mA. If $V_{GS(off)} = -6 \ V$; calculate the value of V_{GS} and V_T . (ii) I_{GSS} of $-2 \ nA$ for $V_{GS} = -20 \ V$. Determine the input resistance.	7	L3	CO2		
	OR						
4	la	Explain the construction, working and characteristics of N-channel depletion MOSFET.	9	L2	CO2		
	b	Explain the working of SCR using two-transistor model.	9	L3	CO2		
	c	For an E-MOSFET, determine the value of I_D , if $I_{D(on)} = 4mA$, $V_{GS(on)} = 6V$, $V_T = 4V$ and $V_{GS} = 8V$.	7	L3	CO2		

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